

# FRED Pt® Gen 5 Ultrafast Single Phase Bridge, 600 V, 30 A



| PRIMARY CHARACTERISTICS                      |                           |  |  |  |  |  |
|--|---------------------------|--|--|--|--|--|
| V <sub>R</sub>                               | 600 V                     |  |  |  |  |  |
| V <sub>F</sub> (typical) at 30 A, per diode  | 1.6 V                     |  |  |  |  |  |
| t <sub>rr</sub> (typical) at 30 A, per diode | 63 ns                     |  |  |  |  |  |
| I <sub>O</sub> at T <sub>C</sub> = 131 °C    | 30 A                      |  |  |  |  |  |
| Type   | Modules - diode, FRED Pt® |  |  |  |  |  |
| Package                                      | SOT-227                   |  |  |  |  |  |
| Circuit configuration                        | Single phase bridge       |  |  |  |  |  |

#### **FEATURES**

- Ultrafast and optimized Q<sub>rr</sub>
- Best in class forward voltage drop and switching losses trade off



- · Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, the VS-U5FH30BA60 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

| ABSOLUTE MAXIMUM RATINGS                                     |                                   |   |             |                  |  |
|--|-----------------------------------|---|-------------|------------------|--|
| PARAMETER  | SYMBOL                            | TEST CONDITIONS   | MAX.        | UNITS            |  |
| Cathode to anode voltage                                     | $V_R$                             |   | 600         | V                |  |
| Continuous forward current per diode                         | I <sub>F</sub>                    | T <sub>C</sub> = 105 °C   | 30          | Α                |  |
| Maximum power dissipation per diode                          | P <sub>D</sub>                    | T <sub>C</sub> = 105°C  | 53          | W                |  |
| Maximum peak one cycle forward non- repetitive surge current | I <sub>FSM</sub>                  | 10 ms or 6 ms rectangular pulse, T <sub>J</sub> = 25 °C, no voltage reapplied | 290         | А                |  |
|  |                                   | 8.3 ms sine, $T_J = 25$ °C, no voltage reapplied                              | 305         |                  |  |
| Maritan and Pharmachally for final and                       | I <sup>2</sup> t                  | No voltage reapplied, t = 10 ms   | 424         | A <sup>2</sup> s |  |
| Maximum I <sup>2</sup> t capability for fusing               |                                   | No voltage reapplied, t = 8.3 ms  | 387         |                  |  |
| Maximum I <sup>2</sup> √t capability for fusing              | I <sup>2</sup> √t                 | t = 0.1 ms to 10 ms, no voltage reapplied                                     | 4244        | A²√s             |  |
| RMS isolation voltage  | V <sub>ISOL</sub>                 | Any terminal to case, t = 1 min   | 2500        | V                |  |
| Operating junction and storage temperature range             | T <sub>J</sub> , T <sub>Stg</sub> |   | -55 to +175 | °C               |  |
| SINGLE PHASE BRIDGE  |                                   |   |             |                  |  |
| Maximum DC output current of bridge                          | Io                                | 180° rect. conduction angle, T <sub>C</sub> = 131 °C                          | 30          | Α                |  |



| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                             |   |      |      |      |       |
|--|-----------------------------|---|------|------|------|-------|
| PARAMETER  | SYMBOL                      | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage   | $V_{BR}$                    | I <sub>R</sub> = 100 μA                         | 600  | -    | -    |       |
| Face and collections   | ard voltage V <sub>FM</sub> | I <sub>F</sub> = 30 A                           | -    | 1.6  | 2.1  | V     |
| Forward voltage  |                             | I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C  | -    | 1.26 | -    |       |
|  |                             | V <sub>R</sub> = 600 V                          | -    | 0.1  | 30   |       |
| Reverse leakage current I <sub>RM</sub>  | I <sub>RM</sub>             | T <sub>J</sub> = 125 °C, V <sub>R</sub> = 600 V | -    | 14   | -    | μΑ    |
|  |                             | T <sub>J</sub> = 150 °C, V <sub>R</sub> = 600 V | -    | 53   | -    |       |

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                              |                                   |   |      |      |      |       |
|---|------------------------------|-----------------------------------|---|------|------|------|-------|
| PARAMETER   | SYMBOL                       | TEST CONDITIONS                   |   | MIN. | TYP. | MAX. | UNITS |
| Payaraa raaayar tima  | ecovery time t <sub>rr</sub> | T <sub>J</sub> = 25 °C            | $I_F = 30 \text{ A},$<br>$di_F/dt = 1000 \text{ A/}\mu\text{s},$<br>$V_R = 400 \text{ V}$ | -    | 57   | -    | ns    |
| neverse recovery time   |                              | T <sub>J</sub> = 125 °C           |   | -    | 62   | -    |       |
| Darl and a second   | I <sub>RRM</sub>             | T <sub>J</sub> = 25 °C            |   | -    | 12   | -    | Α     |
| Peak recovery current   |                              | T <sub>J</sub> = 125 °C           |   | -    | 25   | -    |       |
| Reverse recovery charge   | Q <sub>rr</sub>              | T <sub>J</sub> = 25 °C            |   | -    | 0.3  | -    |       |
|   |                              | T <sub>J</sub> = 125 °C           |   | -    | 0.9  | -    | μC    |
| Junction capacitance  | C <sub>T</sub>               | V <sub>R</sub> = 600 V, f = 1 MHz |   | -    | 29   | -    | pF    |

| THERMAL - MECHANICAL SPECIFICATIONS                                  |                   |                        |      |      |            |             |
|--|-------------------|------------------------|------|------|------------|-------------|
| PARAMETER  | SYMBOL            | TEST CONDITIONS        | MIN. | TYP. | MAX.       | UNITS       |
| Single phase bridge - Thermal resistance junction to case, per diode | R <sub>thJC</sub> |                        | -    | -    | 1.39       | °C/W        |
| Thermal resistance case to heatsink, per module                      | R <sub>thCS</sub> | Flat, greased, surface | -    | 0.05 | -          | C/VV        |
| Weight   |                   |                        | -    | 30   | -          | g           |
| Mounting torque  |                   | Torque per diode       | -    | -    | 1.1 (9.7)  | Nm (lbf.in) |
|  |                   | Torque to heatsink     | -    | -    | 1.8 (15.9) | Nm (lbf.in) |
| Case style   |                   |                        |      | SC   | OT-227     |             |

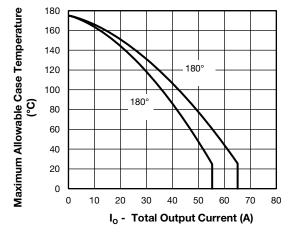


Fig. 1 - Current Rating Characteristics

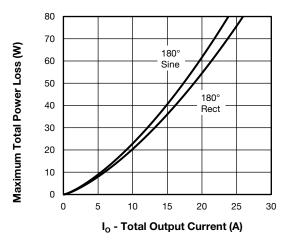


Fig. 2 - Total Power Loss Characteristics

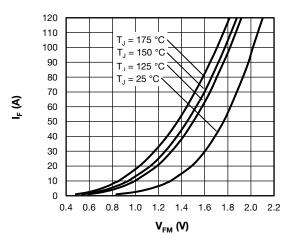


Fig. 3 - Typical Forward Voltage Drop Characteristics

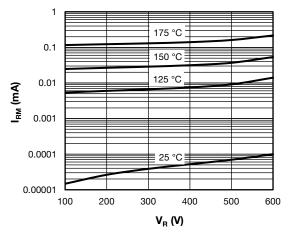


Fig. 4 - Typical Values of Reverse Current

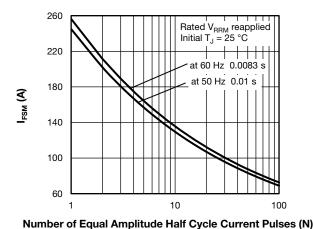


Fig. 5 - Non-Repetitive Peak Forward Surge Current vs. Number Pulses

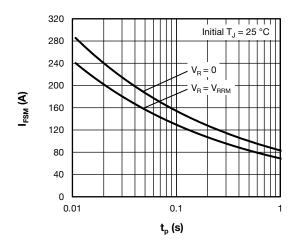


Fig. 6 - Non-Repetitive peak Forward Surge Current vs. Pulse Duration

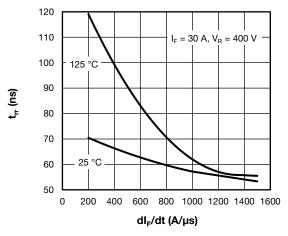


Fig. 7 - Diode Reverse Recovery Time vs. dl<sub>F</sub>dt

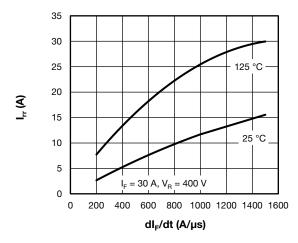
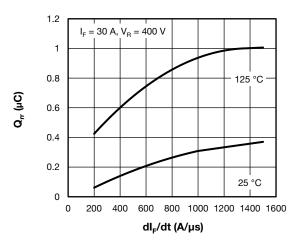


Fig. 8 - Diode Reverse Recovery Current vs. dI<sub>F</sub>dt







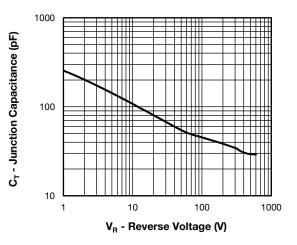


Fig. 10 - Junction Capacitance

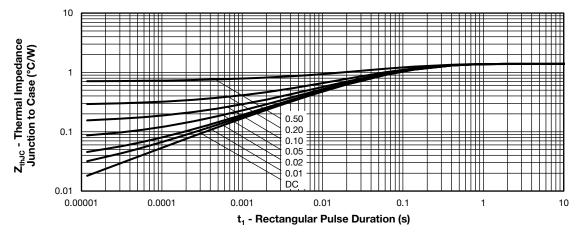
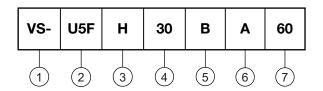


Fig. 11 - Maximum Thermal Impedance Junction to Case

#### **ORDERING INFORMATION TABLE**

#### Device code



1 - Vishay Semiconductors product

- U5F = Gen 5 FRED Pt® family

- H = Ultrafast FRED Pt® diode

- Current rating per module (30 = 30 A)

5 - B = circuit configuration (Single phase bridge)

6 - Package indicator (SOT-227 standard insulated base)

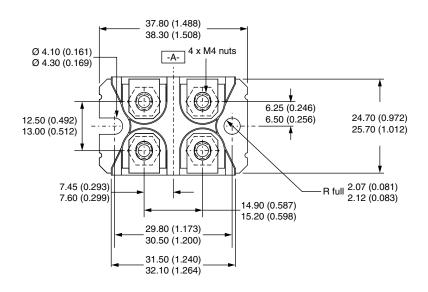
7 - Voltage rating (60 = 600 V)

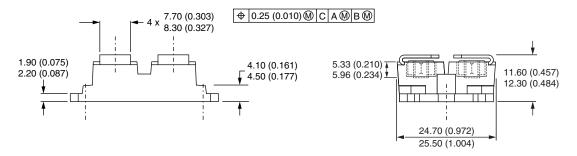
| CIRCUIT CONFIGURATION |                               |   |  |  |  |
|-----------------------|-------------------------------|---|--|--|--|
| CIRCUIT               | CIRCUIT<br>CONFIGURATION CODE | CIRCUIT DRAWING   |  |  |  |
| Single phase bridge   | В                             | 4 (AC) 3 (-) Lead Assignment  4 (AC) 3 (-) Lead Assignment  4 2 (AC) 2 (AC) |  |  |  |

| LINKS TO RELATED DOCUMENTS                            |  |  |  |  |  |
|---|--|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?95423</u>            |  |  |  |  |  |
| Packaging information <u>www.vishay.com/doc?95425</u> |  |  |  |  |  |

## SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)





#### Note

· Controlling dimension: millimeter



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